

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Power MOSFET Dual N-Channel ChipFET™

2.9 Amps, 30 Volts

Features

- Low R_{DS(on)} for Higher Efficiency
- Miniature ChipFET Surface Mount Package Saves Board Space

Applications

• Power Management in Portable and Battery-Powered Products; i.e., Cellular and Cordless Telephones and PCMCIA Cards

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	5 secs	Steady State	Unit		
Drain-Source Voltage	V _{DS}	30		V		
Gate-Source Voltage	V _{GS}	±	20	V		
Continuous Drain Current $(T_J = 150^{\circ}C)$ (Note 1) $T_A = 25^{\circ}C$ $T_A = 85^{\circ}C$	ID	±3.9 ±2.8	±2.9 ±2.1	A		
Pulsed Drain Current	I _{DM}	±10		A		
Continuous Source Current (Diode Conduction) (Note 1)	Is	1.8	0.9	A		
Maximum Power Dissipation (Note 1) T _A = 25°C T _A = 85°C	P _D	2.1 1.1	1.1 0.6	8		
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 to	+150	°C		
1. Surface Mounted on 1" x 1" FR4 Board.						

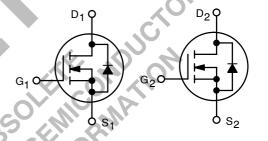
^{1.} Surface Mounted on 1" x 1" FR4 Board.



ON Semiconductor®

http://onsemi.com

DUAL N-CHANNEL 2.9 AMPS, 30 VOLTS $R_{DS(on)} = 85 \text{ m}\Omega$



Channel MOSFET

N-Channel MOSFET



ChipFET CASE 1206A STYLE 2

MARKING PIN CONNECTIONS DIAGRAM D₁] 8 D₁ 2 G₁ 2 [7 A₆ D_2 3 S_2 3 [6 D_2 4 G_2 5 4

A6 = Specific Device Code

ORDERING INFORMATION

Device	Device Package Shippir			
NTHD5902T1	ChipFET	3000/Tape & Reel		

THERMAL CHARACTERISTICS

Characteristic	Symbol	Тур	Max	Unit
$\label{eq:maximum Junction-to-Ambient (Note 2)} $t \le 5 \mbox{ sec} $$ Steady State $$$	R _{thJA}	50 90	60 110	°C/W
Maximum Junction-to-Foot Steady State	R _{thJF}	30	40	°C/W

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Characteristic	Symbol	Test Condition	Min	Тур	Max	Unit
Static						•
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0	-	-	V
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	_	-	± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 24 V, V _{GS} = 0 V	-	-	1.0	μΑ
		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V},$ $T_{J} = 85^{\circ}\text{C}$	-	-	5.0	
On-State Drain Current (Note 3)	I _{D(on)}	$V_{DS} \ge 5.0 \text{ V}, V_{GS} = 10 \text{ V}$	10	- , (), -	Α
Drain-Source On-State Resistance (Note 3)	r _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 2.9 \text{ A}$	_	0.072	0.085	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 2.2 \text{ A}$	-	0.120	0.143	
Forward Transconductance (Note 3)	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 2.9 \text{ A}$	-1	20	_	S
Diode Forward Voltage (Note 3)	V _{SD}	$I_S = 0.9 \text{ A}, V_{GS} = 0 \text{ V}$	(G)	0.8	1.2	V
Dynamic (Note 4)		-0 ¹ / ₁	7 . "	P		•
Total Gate Charge	Qg	22 (1)	Œ,	5.0	7.5	nC
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V},$ $I_{D} = 2.9 \text{ A}$) -	0.8	-	
Gate-Drain Charge	Q_{gd}	16.40	-	1.0	-	
Turn-On Delay Time	t _{d(on)}	4/0	_	7.0	11	ns
Rise Time	t _r	$V_{DD} = 15 \text{ V}, R_L = 15 \Omega$	_	12	18	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 1.0 \text{ A}, V_{GEN} = 10 \text{ V},$ $R_G = 6 \Omega$	_	12	18	
Fall Time	tf		_	7.0	11	
Source-Drain Reverse Recovery Time	Strr	I _F = 0.9 A, di/dt = 100 A/μs	_	40	80	

- Source–Drain Reverse Recovery Time t_{rr}

 2. Surface Mounted on 1" x 1" FR4 Board.
 3. Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2%.
 4. Guaranteed by design, not subject to production testing.

TYPICAL ELECTRICAL CHARACTERISTICS

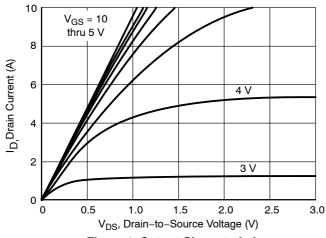


Figure 1. Output Characteristics

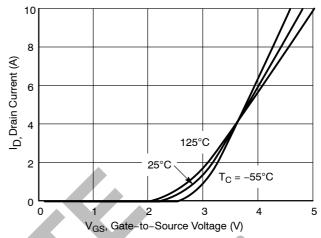


Figure 2. Transfer Characteristics

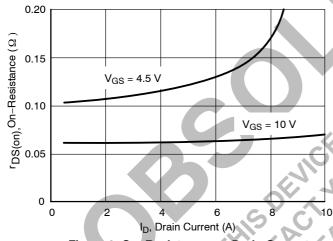


Figure 3. On-Resistance vs. Drain Current

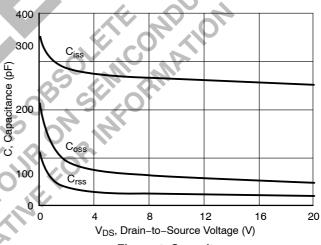
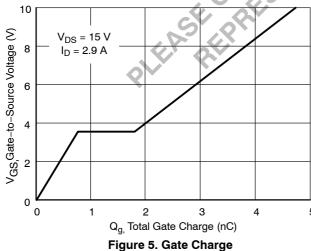


Figure 4. Capacitance



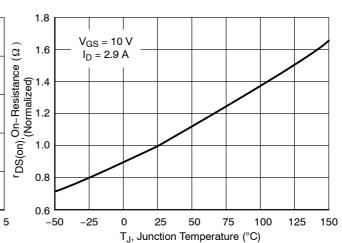


Figure 6. On-Resistance vs. **Junction Temperature**

TYPICAL ELECTRICAL CHARACTERISTICS

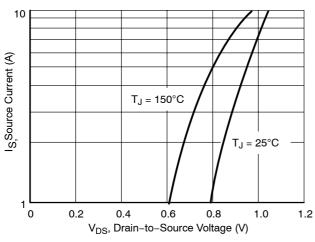


Figure 7. Source-Drain Diode Forward Voltage

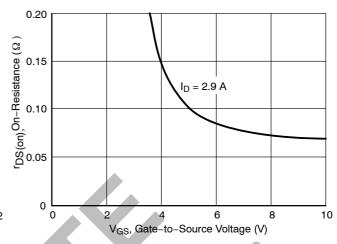


Figure 8. On-Resistance vs. Gate-to-Source Voltage

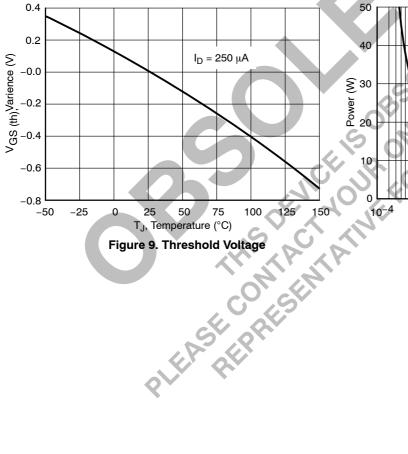


Figure 9. Threshold Voltage

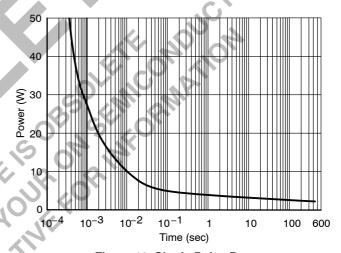


Figure 10. Single Pulse Power

TYPICAL ELECTRICAL CHARACTERISTICS

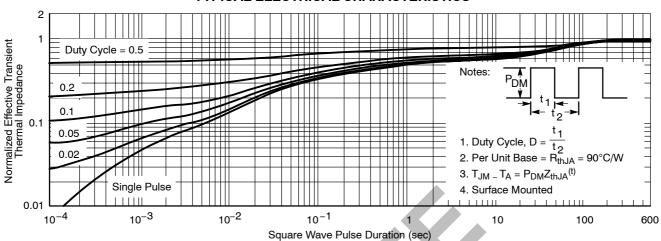
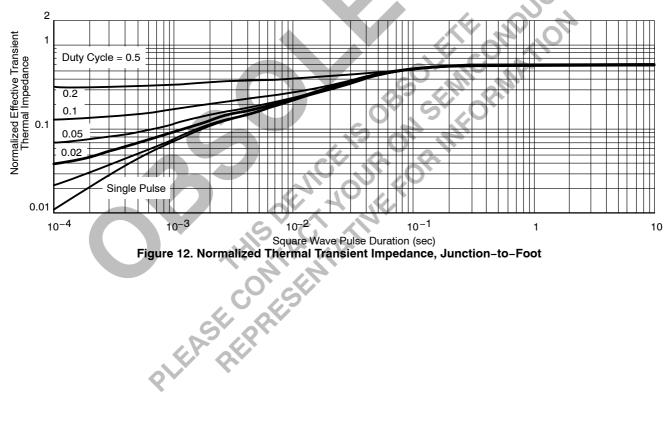


Figure 11. Normalized Thermal Transient Impedance, Junction-to-Ambient

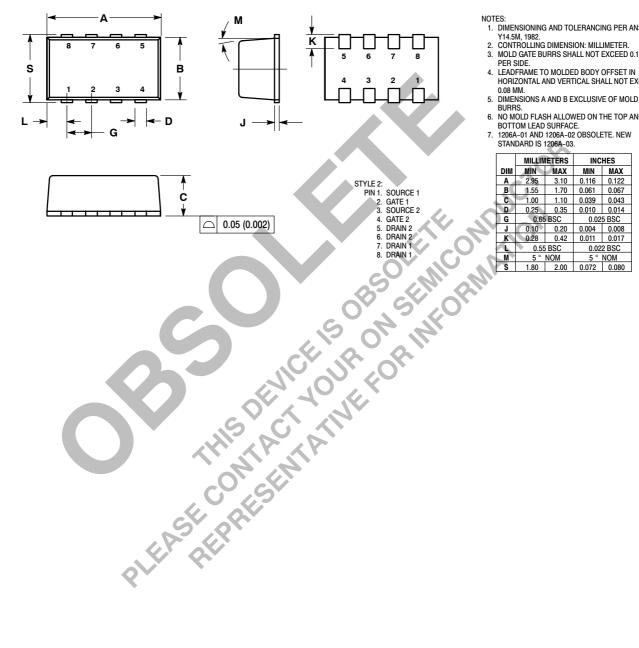


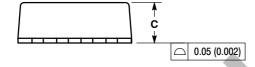
Notes



PACKAGE DIMENSIONS

ChipFET CASE 1206A-03 ISSUE D





NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
 MOLD GATE BURRS SHALL NOT EXCEED 0.13 MM
- PER SIDE.
 LEADFRAME TO MOLDED BODY OFFSET IN
- HORIZONTAL AND VERTICAL SHALL NOT EXCEED 0.08 MM
- DIMENSIONS A AND B EXCLUSIVE OF MOLD GATE BURRS.
- NO MOLD FLASH ALLOWED ON THE TOP AND BOTTOM LEAD SURFACE. 1206A-01 AND 1206A-02 OBSOLETE. NEW

	MILLIN	IETERS	INC	INCHES		
DIM	MIN	MAX	MIN	MAX		
A	2.95	3.10	0.116	0.122		
В	1.55	1.70	0.061	0.067		
o	1.00	1.10	0.039	0.043		
٥	0.25	0.35	0.010	0.014		
G	0.65 BSC		0.025 BSC			
7	0.10	0.20	0.004	0.008		
K	0.28	0.42	0.011	0.017		
Z	0.55 BSC		0.022 BSC			
M	5° NOM		5 ° NOM			
	4 00	0.00	0.070	0.000		



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